# Physics II (PH 102) Electromagnetism (Lecture 10)

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Feb 2020

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- Conductors are materials such as metals, electrolytes (e.g., salt water), graphite, human body, etc., that have a large number of mobile charge carriers, like, electron, ions, etc., that *freely flow* across entire surface of materials and distribute uniformly. They usually have very low resistances.

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- Semi-conductors are usually solid materials, such as silicon, germanium, various alloys, etc., that has conductivities intermediate between insulators and most metals, which often can be regulated in a controlled way, e.g., by the addition impurities (doping) or under temperature variations.

## **Properties of Conductors**

Static Electric field is always zero inside uncharged conductors.

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#### Example

An uncharged conductor is placed in external field **E**<sub>0</sub>.

Positive charges are pushed to right and negative charges to left. These are termed as induced charges, which give rise to the induced Electric field  $E_1$ . The process would continue until  $E_1 = -E_0$ . The net field  $E = E_1 + E_0 = E_1 - E_1 = 0$  inside the conductor.

What happens for the field inside an insulator or a dielectric material ?



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## Properties of Conductors (contd.)



Gauss's Differential Law: Given that the total field **E** is zero inside the conductor, the volume charge density  $\rho$  also vanishes:

 $\rho = \epsilon_0 \nabla \cdot \mathbf{E} = 0$ 

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### Corollary

- Any net charge must reside ONLY on the surface of a conductor.
- Potential is constant throughout a conductor.
- Surface of a conductor represents an equipotential surface.
- Electric field lines are directed perpendicular to the surface just outside a conductor.

### Boundary Conditions for E on the surface of a charged Conductor

Let  $(\hat{\mathbf{n}}, \hat{\mathbf{n}}_{\parallel})$  be the outward (normal, tangent) unit vectors on the smooth conducting interface with charge density  $\sigma = \sigma(\mathbf{r}) = const$ . Let  $\mathbf{E}_{out}(\mathbf{E}_{in})$  be the outside (inside) fields. The BOUNDARY CONDITIONS yield:

$$\mathsf{E}_{ ext{out}}(\mathsf{r}) - \mathsf{E}_{ ext{in}}(\mathsf{r}) = rac{\sigma}{\epsilon_0} \hat{\mathsf{n}}$$
 .

Electric Field at any point immediately outside a conductor is always constant and points perpendicular to the surface.

$$E_{\text{out}}^{\perp}(\mathbf{r}) - \underline{E}_{\text{in}}^{\perp}(\mathbf{r})^{\mathbf{r}} \stackrel{0}{=} \frac{\sigma}{\epsilon_0} = const.$$
$$E_{\text{out}}^{\parallel}(\mathbf{r}) - \underline{E}_{\text{in}}^{\parallel}(\mathbf{r})^{\mathbf{r}} \stackrel{0}{=} 0$$



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## Cavities within Uncharged Conductors



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### Cavities within Uncharged Conductors



## Cavities within Uncharged Conductors: Summary



- The induced charges in a conductor have the same magnitude as the total charge enclosed within cavities.
- The Electric field within cavities of conductors are non-zeros ONLY when they enclose some net amount of charge.

## Capacitors and Capacitance

It is a device used to store electrical charge, consisting of a system of two conductors placed in close proximity of each other (suitably shielded from other charged conductors) having equal and opposite charges ±Q.



## Capacitors and Capacitance (contd.)

The potential difference between the conductors is proportional to the magnitude of the charge Q carried by the conductors

$$\Delta V = V_{+} - V_{-} = -\int_{(-)}^{(+)} \mathbf{E} \cdot d\mathbf{I} \propto Q$$
$$= \left(\frac{1}{C}\right) Q$$
$$C = \frac{Q}{\Delta V} = \frac{Q}{V_{+} - V_{-}}$$

The purely geometrical coefficient C is called the CAPACITANCE and depends on the shapes, sizes and separation of the two conductors.

The capacitance of a capacitor is a measure of its ability to store charge.

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The capacitance of a capacitor is a measure of its ability to store charge.

- ▶ SI Unit: Coulomb per Volt(C/V) or Farad (F).
- The Electrostatic energy stored in a capacitor of charge Q and potential difference  $\Delta V$ :

$$U_E = \frac{1}{2}C(\Delta V)^2 = \frac{1}{2}\frac{Q^2}{\Delta V}$$

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## Capacitances of simple Capacitors Examples

**Spherical** capacitor of radius *R*:

$$C = 4\pi\epsilon_0 R$$

Parallel plate capacitor with area A and separation d:

$$C = \frac{\epsilon_0 A}{d}$$

Concentric spherical capacitor with inner radius a and outer radius b:

$$C = 4\pi\epsilon_0 \left(\frac{ab}{b-a}\right)$$

Coaxial cylindrical capacitor of length L, inner radius a and outer radius b:

$$C = 2\pi\epsilon_0 \frac{L}{\ln\left(\frac{b}{a}\right)}$$

Effective capacitance of parallel system of capacitors:

$$C=C_1+C_2+C_3+\cdots$$

**•** Effective capacitance of series connected capacitors:

$$\frac{1}{C} = \frac{1}{C_1} + \frac{1}{C_2} + \frac{1}{C_3} + \cdots$$

### Solving Boundary-Valued Problems: Limitations of Coulomb & Gauss' Laws

• You are so far familar with solving problems in electrostatics where either a system of charges  $q_i$ , or charge distributions  $(\lambda, \sigma, \rho)$  are supplied. Then you are asked to determine both **E** or *V* using formulas derived from *Coulomb's Law:* 

$$\begin{aligned} \mathbf{E}(\mathbf{r}) &= \frac{1}{4\pi\epsilon_0} \iiint \frac{\rho(\mathbf{r}')\left(\mathbf{r}-\mathbf{r}'\right)}{|\mathbf{r}-\mathbf{r}'|^2} d\mathbf{v}' \\ V(\mathbf{r}) &= \frac{1}{4\pi\epsilon_0} \iiint \frac{\rho(\mathbf{r}')}{|\mathbf{r}-\mathbf{r}'|} d\mathbf{v}' \end{aligned}$$

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For problems with high degrees of symmetry you could use Gauss's Integral Law to first determine E and then determine V:

$$\oint \mathbf{E}(\mathbf{r}) \cdot dS = \frac{1}{\epsilon_0} Q_{\text{encl}}$$

$$\Rightarrow V(\mathbf{r}) = -\int_{-\infty}^{\mathbf{r}} \mathbf{E}(\mathbf{r}) \cdot d\mathbf{I}$$

Solving Boundary-Valued Problems: Limitations of Coulomb & Gauss' Laws

You are so far familar with solving problems in electrostatics where either a system of charges q<sub>i</sub>, or charge distributions (λ, σ, ρ) are supplied. Then you are asked to determine both E or V using formulas derived from Coulomb's Law:

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$$\implies \qquad V(\mathbf{r}) = -\int_{\infty}^{\mathbf{r}} \mathbf{E}(\mathbf{r}) \cdot d\mathbf{I}$$

These approaches become useless if the charges or charge densities are a priori NOT supplied.

**The Problem:** In many practical Electrostatic problems involving a system of conductors (i = 1, 2, ..., n) in a certain region, the charge distributions may not be a priori known, but instead, either the Potentials  $V_i$ , Electric Fields  $E_i$ , or the total charges  $Q_i$  may be only specified on the surfaces of different conductors. How to determine solutions of  $V(\mathbf{r})$ ,  $\mathbf{E}(\mathbf{r})$  or  $\rho(\mathbf{r})$  for all space?

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First require solving for the **Potential** V(r) everywhere by solving either:

 $abla^2 V(\mathbf{r}) = -\frac{\rho(\mathbf{r})}{\epsilon_0} \implies \text{Poisson's Equation}$  $abla^2 V(\mathbf{r}) = 0 \implies \text{Laplace's Equation}$ 

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- Using 2 different Methods of Boundary Conditions:
  - 1. Solving via the special technique called "Method of Images"
  - 2. Rigorously solution of Laplace's Eqs. (2<sup>nd</sup> order PDEs):

Especially, we will solve Laplace's Equations in charge free regions in Cartesian System using the method of SEPARATION OF VARIABLES :

$$\nabla^2 V(x, y, z) \equiv \frac{\partial^2 V}{\partial x^2} + \frac{\partial^2 V}{\partial y^2} + \frac{\partial^2 V}{\partial z^2} = 0 \implies V(x, y, z) = X(x)Y(y)Z(z)$$

## Boundary-Valued Problems: Schematic Domain for Solving $\nabla^2 V(\mathbf{r}) = 0$

• Our interest is particularly to obtain a solution to the Potential  $V(\mathbf{r})$  in a charge free  $\rho(\mathbf{r}) = 0$  region:  $\mathbf{r} \in \mathcal{D} \subset \mathbb{R}^3$ , bounded by one or multipple closed surfaces  $S_1, S_2, S_3 \cdots$ 



Note: D is free of charge distributions, but there may be plenty of charge distributions and charged conductors elsewhere in ℝ<sup>3</sup>. In case there are no charges anywhere, the solution becomes trivial, i.e., V(r) = 0, const. ∀ℝ<sup>3</sup>.

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- The solutions to the Laplace's equations are called HARMONIC FUNCTIONS. They have 2 very special properties:
- 1. They attain extrema only at the boundaries of the domain  $\mathcal{D}$  of their definition; otherwise they are rather "monotonic" functions without any local maxima or minima at interior points in  $\mathcal{D}$ .

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2. Their values at any given interior point P in the domain D is the average over their values about ANY closed interval around P.

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#### Geometrical Interpretations :

1. In 1D, the solution yields the shortest distance between the two given boundary points, i.e., a straight line.

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#### Geometrical Interpretations :

- 1. In 1D, the solution yields the shortest distance between the two given boundary points, i.e., a straight line.
- 2. In 2D, the solution minimizes the surface area between given boundary curves.

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#### Geometrical Interpretations :

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- 2. In 2D, the solution minimizes the surface area between given boundary curves.
- 3. In 3D, geometrical interpretations of solutions are in general difficult to visualize. The only way to interpret:

For a given set of boundary conditions they yield maximally monotonic solns!

Consequences of Harmonic Nature of Solutions in 1D

# Example



- → It contains two undetermined constants (m and b)
- $\rightarrow$  (m and b) are fixed, in any particular case, by the boundary conditions of that problem.

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### Call attention to two features of this result

1. V(x) is the average of V(x + a) and V(x - a), for any a:

$$V(x) = \frac{1}{2} [V(x+a) + V(x-a)]$$

→ Laplace's equation is a kind of averaging instruction

2. Laplace's equation tolerates no local maxima or minima

➔ Extreme values of V must occur at the end points

## Consequences of Harmonic Nature of Solutions in 2D

# Example

If V depends on two variables,

$$\frac{\partial^2 V}{\partial x^2} + \frac{\partial^2 V}{\partial y^2} = 0$$

This is no longer an ordinary differential equation

- → it is a partial differential equation
- → general solution to this equation doesn't contain just two arbitrary constants despite the fact that it's a second order equation.

→ the boundary conditions  $\longrightarrow$   $V(\mathbf{r}(t_b)) = f(t_b)$ ;  $t_b \in \mathbb{R} \rightarrow \text{variable parameter}$ , specified at all points on the boundary curve.

### Nevertheless, possible to deduce certain properties common to all solutions.

- 1. The value of V at a point (x, y) is the average of those around the point.
  - → If you draw a circle of any radius R about the point (x, y), the average value of V on the circle is equal to the value at the center:

$$V(x, y) = \frac{1}{2\pi R} \oint_{\text{circle}} V \, dl$$

### 2. V has no local maxima or minima; all extrema occur at the boundaries.

- → Laplace's equation picks the most featureless function possible, consistent with the boundary conditions:
- $\rightarrow$  Laplace's equation picks no hills, no valleys, just the smoothest surface available.



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Find the average potential over an imaginary constructed spherical surface S of radius R with center P, located in a charge free domain  $\mathcal{D}$  at a distance  $d \gg R$  from a far away point charge q located outside  $\mathcal{D}$ .

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• Electrostatic Potential at P:  $V(P) = \frac{q}{4\pi\epsilon_0 d}$ 

• Average Potential on surface  $S(dS = R^2 \sin \theta \, d\theta \, d\phi)$ :

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$$\langle V \rangle_{S} = \frac{1}{4\pi R^2} \oint_{S} V(\mathbf{r}(R,\theta,\phi)) \, dS$$



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Electrostatic Potential at P: V(P) =  $\frac{q}{4\pi\epsilon_0 d}$ Average Potential on surface S ( $dS = R^2 \sin \theta \, d\theta \, d\phi$ ):  $\langle V \rangle_S = \frac{1}{4\pi R^2} \oint_S V(\mathbf{r}(R, \theta, \phi)) \, dS$ as  $dS = \frac{1}{4\pi R^2} \frac{q}{4\pi\epsilon_0} \int_{\phi=0}^{\phi=2\pi} \int_{\theta=0}^{\theta=\pi} \frac{R^2 \sin \theta \, d\theta \, d\phi}{\sqrt{R^2 + d^2 - 2Rd\cos\theta}}$ 

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Potential at the point P due to the distant point charge is same as the average Potential over the spherical surface S centered at P. By Superposition Principle, the same is true for any collection of distant point charges.

**Theorem** 

Let  $\mathcal{D}$  be a charge free region in  $\mathbb{R}^3$  with point P located within this domain. If S is any spherical surface in  $\mathcal{D}$  centered at P, then the net Electrostatic Potential at P due to any collection of distant point charges located outside  $\mathcal{D}$  is equal to the average of the net Electrostatic Potential over S.

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### Proof.

Consider the collection of distant point charges  $q_1, q_2, \ldots, q_n$ , all placed outside  $\mathcal{D}$ , and  $V_1, V_2, \ldots, V_n$  be the potentials at  $P \in \mathcal{D}$  due to these charges. Then, we know  $1 \quad \iint_{\mathcal{D}} P(Q) = 0$ 

$$V_i(P) = \langle V_i \rangle_S = rac{1}{\operatorname{Area}} \oiint_S V_i(\mathbf{r} \in S) \, dS$$

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So, the net Potential at P by **Superposition Principle** is

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So, the net Potential at P by **Superposition Principle** is

$$\begin{aligned} V_{\text{net}}(P) &= \sum_{i=1}^{n} V_i(P) \\ &= \sum_{i=1}^{n} \langle V_i \rangle_S = \frac{1}{\text{Area}} \oint_S \left[ \sum_{i=1}^{n} V_i(\mathbf{r} \in S) \right] dS \\ &= \frac{1}{\text{Area}} \oint_S \left[ V_{\text{net}}(\mathbf{r} \in S) \right] dS = \langle V_{\text{net}} \rangle_S \end{aligned}$$

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Corollary

(1) If  $\mathcal{D}$  be a charge free region  $\subset \mathbb{R}^3$ , then there CAN NOT be any local maxima or minima in the solution to the Electrostatic Potential anywhere IN-TERIOR within  $\mathcal{D}$ . All extremities must occur at the BOUNDARIES of  $\mathcal{D}$ .

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(2) Let  $\mathcal{D}$  be a charge free region  $\subset \mathbb{R}^3$  such that the Electrostatic Potential is constant on all its boundaries. Then the MONOTONIC nature of the solution demands that the Electrostatic Potential has the same CONSTANT value throughout  $\mathcal{D}$ .

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#### Note:

- ▶ If the charge free region  $\mathcal{D} \equiv \mathbb{R}^3$ , then the boundary condition,  $V = const. \forall r \in S_{\infty}$ , implies trivial solution V = const. everywhere in  $\mathbb{R}^3$ .
- For a region with charge distributions, V satifies the Poisson's Equation, which does not guarantee a HARMONIC (monotonic) solution.

### Uniqueness Theorem

Solutions to PDEs like, the Laplace's or Poisson's Equations, can be obtained in a variety of different ways in general. Moreover there are infinite number of solutions depending on different boundary conditions. Fortunately, the so-called **Uniqueness Theorem** guarantees the solution to be unique regardless of the methodology used provided there exists a unique set of boundary conditions.

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#### Theorem

**First Uniqueness Theorem:** Let  $\mathcal{D} \in \mathbb{R}^3$  be a region free of charge with a smooth boundary surface S and  $\alpha : S \to \mathbb{R}$  be any arbitrary smooth function defined on the boundary points  $\mathbf{S} \in S$ . Then the Laplace's equation,

$$\nabla^2 V(\mathbf{r}) = 0 \quad over \mathcal{D},$$

given the b.c. that,  $V(S) = \alpha(S)$  on S,

always guarantees a unique solution.

## Proof.

First, assume that two solutions  $V_1(\mathbf{r})$  and  $V_2(\mathbf{r})$  to the Laplace's equations in the "simple" charge fee region  $\mathcal{D}$ , assuming the <u>same</u> boundary condition that,

$$V_1(\mathbf{S}) = V_2(\mathbf{S}) = \alpha(\mathbf{S}) \qquad \forall \mathbf{S} \in S$$

for an arbitrary smooth function lpha on the "simple" boundary surface  ${\it S}$ , i.e.,

$$\begin{aligned} \nabla^2 V_1(\mathbf{r}) &= 0 \qquad \forall \mathbf{r} \in \mathcal{D}, \\ \nabla^2 V_2(\mathbf{r}) &= 0 \qquad \forall \mathbf{r} \in D. \end{aligned}$$

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Next, define function  $V_3 = V_1 - V_2$ , then  $V_3$  also satisfies Laplace's equation:

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$$\nabla^2 V_3 = \nabla^2 V_1 - \nabla^2 V_2 = 0 \quad , \quad \text{over } \mathcal{D},$$
such that,  $V_3(\mathbf{S}) = V_1(\mathbf{S}) - V_2(\mathbf{S}) = \alpha(\mathbf{S}) - \alpha(\mathbf{S}) = 0 \quad , \quad \text{on } S.$ 

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**Use Corollaries (1) & (2)**: Solutions to Laplace's equation tolerates no local extrima within the region D; all extrima must occur only at the boundary S.

Since,  $\nabla^2 V_3 = 0$  over  $\mathcal{D}$ , and  $V_3 = 0$  on S, it must imply  $V_3 = 0$   $\forall r \in \mathcal{D}$ .

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$$\hookrightarrow V_1(\mathbf{r}) = V_2(\mathbf{r}) \qquad \forall \mathbf{r} \in \mathcal{D},$$

i.e., both solutions are identical !

## Second Uniqueness Theorem: Charged regions and Conductors

#### Theorem

**Second Uniqueness Theorem:** If  $\mathcal{V} \subset \mathbb{R}^3$  be a region surrounded by a system of charged conductors and filled with a specified charge density  $\rho$ , then the Electric Field **E** is uniquely determined by specifying the total charge on each conductor.



Proof.

First, assume two solutions,  $E_1(r) = -\nabla V_1(r)$  and  $E_2(r) = -\nabla V_1(r)$  in the space between the conductors in region  $\mathcal{V}$ , satisfying the differential form of Gauss's law:

$$abla \cdot \mathbf{E}_1(\mathbf{r}) = rac{
ho(\mathbf{r})}{\epsilon_0} \qquad \& \qquad 
abla \cdot \mathbf{E}_2(\mathbf{r}) = rac{
ho(\mathbf{r})}{\epsilon_0}.$$

 ${\sf Proof}.$ 

First, assume two solutions, E₁(r) = −∇V₁(r) and E₂(r) = −∇V₁(r) in the space between the conductors in region V, satisfying the differential form of Gauss's law:

$$abla \cdot \mathsf{E}_1(\mathsf{r}) = rac{
ho(\mathsf{r})}{\epsilon_0} \qquad \& \qquad 
abla \cdot \mathsf{E}_2(\mathsf{r}) = rac{
ho(\mathsf{r})}{\epsilon_0}.$$

For surfaces S<sub>1</sub>,..., S<sub>n</sub>, enclosing the conductors with charges Q<sub>1</sub>,..., Q<sub>n</sub> (integral form of Gauss's law):

$$\iint_{S_i} \mathsf{E}_1 \cdot d\mathsf{a} = \frac{Q_i}{\epsilon_0} \qquad \& \qquad \iint_{S_i} \mathsf{E}_2 \cdot d\mathsf{a} = \frac{Q_i}{\epsilon_0}$$

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▶ Likewise, for the outer boundary S of V enclosing total charge  $Q_{tot}$ :

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 $\blacktriangleright$  Likewise, for the outer boundary S of  $\mathcal{V}$  enclosing total charge  $Q_{tot}$ :

Next we define a new vector field E<sub>3</sub> in V:

$$\begin{aligned} \mathbf{E}_3(\mathbf{r}) &= \mathbf{E}_1(\mathbf{r}) - \mathbf{E}_2(\mathbf{r}) \\ -\nabla V_3(\mathbf{r}) &= -\nabla (V_1 - V_2), \quad \forall \mathbf{r} \in \mathcal{V} \end{aligned}$$

**E**<sub>3</sub> must satisfy:

$$\nabla \cdot \mathbf{E}_{3}(\mathbf{r}) = 0, \ \forall \mathbf{r} \in \mathcal{V} \qquad \& \qquad \oiint_{\mathsf{all surfaces}} \mathbf{E}_{3} \cdot d\mathbf{a} = 0, \quad \forall \mathbf{S} \in \{\mathcal{S} \cup S_{1} \cup ... \cup S_{n}\}.$$

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▶ Now, on the surface of each conductor,  $S_1, ..., S_n$ :

$$V_1(\mathbf{S}_i) = C_{1i}(const.) \quad \& \quad V_2(\mathbf{S}_i) = C_{2i}(const.), \quad \mathbf{S}_i \in S_i$$
  
$$\Rightarrow V_3(\mathbf{S}_i) = V_1(\mathbf{S}_i) - V_2(\mathbf{S}_i) = C_{3i} \implies \text{ again a constant.}$$

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▶ If we extend V to include **ALL SPACE**:  $V \to \mathbb{R}^3$  and  $S \to S_\infty$ , then

$$V_{3}(\mathcal{S}) 
ightarrow V_{3}(\mathcal{S}_{\infty}) = 0 \implies$$
 also a constant.

**E**<sub>3</sub> must satisfy:

$$abla \cdot \mathsf{E}_3(\mathsf{r}) = 0, \ orall \mathsf{r} \in \mathcal{V} \qquad \& \qquad \oint _{\mathsf{all surfaces}} \mathsf{E}_3 \cdot d\mathsf{a} = 0, \quad \forall \mathsf{S} \in \{\mathcal{S} \cup S_1 \cup ... \cup S_n\} \,.$$

Now, on the surface of each conductor,  $S_1, ..., S_n$ :

$$V_1(\mathbf{S}_i) = C_{1i}(const.) \quad \& \quad V_2(\mathbf{S}_i) = C_{2i}(const.), \quad \mathbf{S}_i \in S_i$$
$$\Rightarrow V_3(\mathbf{S}_i) = V_1(\mathbf{S}_i) - V_2(\mathbf{S}_i) = C_{3i} \implies \text{ again a constant.}$$

▶ If we extend  $\mathcal{V}$  to include **ALL SPACE**:  $\mathcal{V} \to \mathbb{R}^3$  and  $\mathcal{S} \to \mathcal{S}_\infty$ , then  $V_3(\mathcal{S}) \to V_3(\mathcal{S}_\infty) = 0 \implies$  also a constant.

 $\blacktriangleright$  Thus, we conclude that  $V_3$  is constant for ALL surfaces in  $\mathcal{V} 
ightarrow \mathbb{R}^3$ , i.e.,

$$V_3(\mathbf{S}) \rightarrow consts. \ \forall \mathbf{S} \in \{S \cup S_1 \cup ... \cup S_n\}$$

► Recall Identity:

 $\nabla \cdot (V_3 \mathsf{E}_3) = V_3 (\nabla \cdot \mathsf{E}_3) + (\nabla V_3) \cdot \mathsf{E}_3$ 

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**Recall Identity**:

$$\nabla \cdot (V_3 \mathbf{E}_3) = V_3 (\nabla \cdot \mathbf{E}_3) + (\nabla V_3) \cdot \mathbf{E}_3 = V_3 (\nabla - \mathbf{E}_3)^{-0} |\mathbf{E}_3|^2 = -E_3^2$$

 $\blacktriangleright$  Applying Gauss's Divergence Theorem to the region  $\mathcal{V} \to \mathbb{R}^3 {:}$ 

$$\iiint_{\mathbb{R}^3} \nabla \cdot [V_3(\mathbf{r}) \mathbf{E}_3(\mathbf{r})] d\tau = \bigoplus_{\mathsf{all surfaces}} [V_3(\mathbf{S}) \mathbf{E}_3(\mathbf{S})] \cdot d\mathbf{a} = \sum_i C_{3i} \bigoplus_{S_i} C_{3i} d\mathbf{a} = 0$$
$$\implies \iiint_{\mathbb{R}^3} \nabla \cdot [V_3(\mathbf{r}) \mathbf{E}_3(\mathbf{r})] d\tau = - \iiint_{\mathbb{R}^3} E_3^2(\mathbf{r}) d\tau = 0$$

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• Since the integrand 
$$E_3^2 > 0 \Longrightarrow E_3 = 0$$
.

Consequently,

.

$$\mathsf{E}_1=\mathsf{E}_2, \; \forall \mathsf{r} \in \mathbb{R}^3$$

# Example

Show that the potential is *constant* inside an enclosure completely surrounded by conducting material, provided there is no charge within the enclosure

- ightarrow potential on the cavity wall is some constant,  $V_0$
- $\rightarrow$  potential inside is a function that satisfies Laplace's equation and has the constant value  $V_0\,$  at the boundary

 $abla^2 V(\mathbf{r}) = 0$  inside cavity;  $V(\mathbf{r}) = V_0$  on cavity wall

- $\rightarrow$  V = V<sub>0</sub> everywhere inside enclosure
- → uniqueness theorem guarantees that this is the only solution

→ It follows that the *field* inside an empty cavity is zero.